Sc substitution for M g in M gB2: e ects on Tc and K ohn anom aly

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Here we report synthesis and characterization of M g1 $_{\rm x}\,{\rm Sc_x}\,{\rm B_2}$ (0.12< x<0.27) system , with critical tem perature in the range of 30> T c> 6 K . We not that the Sc doping m oves the chem ical potential through the 2D/3D electronic topological transition (ETT) in the band where the \shape resonance" of interband pairing occurs. In the 3D regime beyond the ETT we observe a hardening of the E $_{\rm 2g}$ R am an mode with a signicant line-width narrowing due to suppression of the K ohn anomaly over the range 0< q< $2k_{\rm F}$.

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Following the discovery of superconductivity in M qB2 with a T $_{\rm c}$ of 40 K $^{\rm 1}$ large attention has been paid to chem ical substitutions^{2,3,4,5,6,7,8} aim ing at enhancem ent of T_G and H_{c2} , and to manipulate the electronic structure for the understanding of the high T $_{\text{c}}$ superconductivity. A s a matter of fact, chemical substitution in the M gB_2 is dicult and only Alreplacing Mg^{4,5,6,7} and Creplacing B⁸ had been successful. Both of these substitutions reduce the T_c and induce a lattice compression. The variation of T c with doping is mostly determined by the tuning of the chemical potential through the electronic topological transition (ETT) where the topology of the Ferm i surface of the band changes from 2D to 3D 6. In this two-gap superconductor9 the exchange-like nondiagonal - interband pairing terms that enhance Tc are expected to exhibit large variation near the ETT 5,6 . In addition, Ram an spectroscopy measurements on the M g_{1 x}A l_x B₂ and M gB_{2 x}C_x system s^{10,11,12,13} have revealed a line-width narrowing and energy hardening of the $E_{2\alpha}$ -m ode with the substitution beyond the ETT. This e ect could be interpreted in term of suppression of the Kohn anomaly 14,15 observed over an extended range $0 < q < 2k_F$ in the M gB₂^{16,17} by a shift of the Ferm i level. In fact the Kohn anomaly 18 is strong (weak) for a 2D (3D) Ferm i surface 19,20. Therefore it is expected to decrease for a 2D to 3D ETT 6,20 of the Fermi surface. The proximity to an ETT has been invoked to explain the anom alous pressure dependence²² of this mode and it has been proposed to be the driving mechanism for raising the critical tem perature 6,23,24. The aim of this work is to modify the band structure by chemical substitutions

to explore the role of electronic structure in the M gB_2 on the electron-phonon coupling and on T_c by tuning the chem ical potential through the shape resonance.

We have synthesized the new superconducting termary system M $g_{1-x} Sc_x B_2$ for 0.12 < x < 0.27, where the chem ical substitution induces m inor lattice variations since the ionic radius of Sc $(1.62\,\mathrm{A})$ is only a little larger than of M g $(1.602\,\mathrm{A})$. The substituted Sc ions donate 0.12 < x < 0.27 electrons per unit cell to the conduction—and—bands so the chem ical potential is shifted towards the top of the—band beyond the ETT 6 where the—Ferm i surface changes from a 2D to a 3D topology, expected near $x=0.12^{9,18}$. Sc substitution for M g increases the disorder in the M g/Sc layers but has m inor e-ects on the lattice structure of the boron layer. Therefore the variation of T_c and electron-phonon coupling with the variation of the electron structure can be well investigated.

In these new samples we observe a remarkable line narrowing and frequency hardening of the E $_{2g}$ R am an mode, which gives a compelling experimental evidence for a drastic reduction of the Kohn anomaly and of the electron phonon coupling for x>0.12. It is remarkable to note that the critical temperature in the M g_{1} $_{x}$ Sc $_{x}$ B $_{2}$ samples has been dropped only by a factor 2-10 from M $_{y}$ B $_{z}$, much less than expected for a multi-band theory (with doping-independent interband pairing) considering the decrease of the electron-phonon coupling and of the density of states in the band. This suggests importance of the resonant enhancement of the interband pairing term 23 and the associated minimum of the non-diagonal coulomb pseudo-potential 24 that drives the T $_{c}$

am pli cation at the ETT, called \shape resonance" in a two-gap superconductor.

M g_{1} xSc_xB₂ sam ples were synthesized by direct reaction m ethod of the elemental magnesium and scandium (powder, 99.9 mass % nominal purity), boron (99.5 % pure < 60 mesh powder). The starting materials were mixed in a stoichiometric ratio and pressed into pellets of 8 mm in diameter. Each pellet was enclosed in a tantalum crucible and sealed by arc welding under argon atmosphere. The Ta crucibles were then heated in a furnace Centorr M 60 under high-pure A r atmosphere for 14 hours in the temperature range between 1280 and 950 °C.

The phase purity of the samples was checked by Xray di raction. The di raction patterns of M q x Scx B2 sam ples were measured in the Bragg-Brentano - geom etry by a vertical X Pert Pro MPD di ractom eter using a Cu K radiation. The X-ray di raction measurements of several sam ples were repeated at the beam line ID 31 of the European Synchrotron Radiation Facility (ESRF), Grenoble. The samples were sealed in 1.0 mm diameter glass capillaries and the high-resolution di raction pro les (=0.5A) were collected at T=80 K using nine Ge(111) analyzer crystals. The re ections were indexed to a M gB2-like structure according to the hexagonal A B2 structure type (P6/mmm space group). No Sc, Sc2O3 or ScB₁₂ m inority phases were found, which indicates a successful Sc substitution for M g. Figure 1a shows pro les of (002) and (110) di raction peaks for representative sam ple of the M g_1 $_x$ Sc_x B_2 system . A line broadening is observed in Sc-doped compounds as compared to MgB2 and ScB2 indicating disorder or non-uniform ities due to M g/Sc layers.

The samples were characterized for their superconducting properties by the temperature dependence of complex conductivity using the single-coil inductance method^{5,6}. The temperature dependent radio-frequency complex conductivity for representative Sc contents is shown in Fig. 1b where it can be seen that the introduction of Sc in the Mg-planes induces a clear shift of the superconducting transition to lower temperatures. The superconducting transition for the Sc-doped samples shows a broadening. This indicates that some disorder does exist in the Sc-doped samples with possible election the superconductivity via an increase of intraband scattering in the band.

The Raman spectra were measured in the backscattering geometry, using a T 64000 Jobin-Y von triple spectrom eter with a charge-coupled device camera. The explored Raman shift ranges between 200 and 1100 cm $^{-1}$. The 488.0 nm Ar $^{\pm}$ laser line was focused on 1-2 m large crystallites and the power was kept below 0.03 mW to avoid heating by the beam. Typical spectra recorded for selected temperatures are shown in Fig. 1c. The in-plane Boron vibration with E $_{\rm 2g}$ symmetry produces a single narrow peak in Raman spectrum of ScB $_{\rm 2}$ as in A $_{\rm 1B}^{-10,12}$ also if at lower energy according with its larger lattice parameters. The Raman line is softened going from ScB $_{\rm 2}$

to M $g_{1}\ _{x}Sc_{x}B_{2}$ and $\$ nally becomes very soft and very broad in M gB_{2} .

The di raction data were analyzed by Rietveld re nem ent using GSAS program. The behaviour of the lattice param eters a and c as a function of Sc content is reported in Fig. 2. A miscibility gap occurs in the range from 2 1% to 12 1% Sc substitution where the samples show a macroscopic phase separation between low-doped and high-doped samples. The a-axis increases gradually with increasing Sc-content, while the c-axis is nearly constant. The unit cell volume shows a small expansion in agreem ent with the similar ionic radius between Sc^{3+} and $M g^{2+}$. For comparison in the same gure we report the evolution of the lattice parameters in the M g_1 $_xA$ l_xB_2 system that shows much larger lattice variations. Here \x" is the nom inal Sc-content and we can conclude that the introduced Sc is successfully substituted for M q, and the actual Sc-content is not much dierent from the nominal value. From the variation of lattice param eters with Sc content, we can conclude that the solubility range of Scandium in MgB₂ is between 12% and 27%.

The variation of the superconducting critical tem perature T $_{\rm c}$ as a function of Sc doping is reported in the panel (a) of F ig. 3. The transition tem perature T $_{\rm c}$ was determined from the peak in derivative of the complex conductivity. The T $_{\rm c}$ decreases continuously with increasing Sc substitution from 30K at 12% to 6K at 27% . It is interesting to note that the variation of T $_{\rm c}$ (x) is sharper for 0.12< x< 0.15.

The panel (b) of Fig. 3 shows the variation of the frequency of the $\rm E_{2g}$ Ram an line from M gB $_2$ to M gI $_{\rm x}\rm Sc_{\rm x}\rm B_2$. The error bars indicate the E $_{\rm 2g}$ peak half-width. In the Sc-substituted samples in the range 12% -27% the phonon peak is shifted toward higher frequency, it is much narrower in comparison with M gB $_2$ and it is approaching the frequency of that for the ScB $_2$. The frequency hardening and the line-width narrowing of the Ram an E $_{\rm 2g}$ m ode indicates a clear decrease of the electron-phonon coupling going from M gB $_2$ to the Scdoped samples.

Finally in Fig. 4 we report the energy of the Ram an E $_{2g}$ m ode as a function of the a-axis (that is the relevant parameter for the in plane high frequency longitudinal optical mode E $_{2g}$) of the non-superconducting diborides ScB $_2$ and A B $_2$, and of the superconducting M gB $_2$, M g $_1$ xScxB $_2$ and M g $_0$:5A $_0$:5B $_2$ ¹³ system s.

Let us consider $\,$ rst the A $\, \rm B_2 \,$ and ScB $_2 \,$ sam ples w ith a led $\,$ band. The energy of the E_{2g} m ode as a function of a-axis follows the law $\,$ (a) = $!_{\rm A\, 1} (a=a_{\rm A\, 1})^{-3}$ $^{\rm 0\, a}$ (dashed line in panel a) where $\,$ $_{\rm 0\, a}$ is the G runeisen parameter $\,$ $_{\rm 0\, a}$ = $\,$ 0 ln = 30 ln a = 1.4 0.1 that is the expected behaviour due to lattice expansion for a m etallic covalent m aterial.

In the case where the Fermi level is tuned below the top of the band (e.g. MgB₂, Mg₁ $_x$ Sc_xB₂ and Mg_{0:5}A $l_{0:5}$ B₂) a phonon decay channel opens up unlike others with led band (e.g. AB₂ and ScB₂). In fact the phonons can now decay into electron-hole exci-

tations in the band inducing a phonon energy softening and line broadening (K ohn anomaly). The E_{2g} phonon softening can be obtained by the energy dierence between the experimental E_{2g} R am an energy $!_{E_{2g}}$ and the expected phonon energy E_{2g} (a) for a material with a

lled band and with the appropriate lattice parameter. We deduce the large phonon softening of 37 meV for M qB_2 and about 17 m eV for M $q_1 \times Sc_x B_2$ system that is close to the case of M $g_{0.5}Al_{0.5}B_2$. The Ram an softening in M gB2 is due to large electron-phonon interaction with the electron-hole excitations in the that drives the system close to a lattice instability and the breakdown of Migdal approximation 9,18. The decrease of the electron-phonon coupling near q= 0 going from MgB2 to Mg1 $_{x}$ Sc $_{x}$ B2 is given by the variation of the ratio $(E_{2q}(q=0)=!E_{2q}(q=0))^2$ shown in panel (b) going from 2.2 in M gB $_2$ to 1.4 in M g $_{0:8}$ Sc $_{0:2}$ B $_2$. This drastic decrease is related to a smaller E $_{
m 2g}$ K ohn anom aly in M q_{1 x} Sc_x B₂. This result is con m ed by the variation of the ratio between the line-width and the phonon energy 2 = $!_{E_{2g}}$ shown in panelc of Fig. 4 that decreases going from M gB $_2$ to M g0 $_{:8}\,\mathrm{Sc}_{0\,:2}\,\mathrm{B}_{\,2}\,$. These results can be understood if the Sc substitution has driven the chem icalpotentialthrough the ETT where the Ferm isurface has a 3D topology⁶ with a reduced Kohn anomaly^{14,15}.

In conclusion we have reported the successful substitution of Sc for M g with 0.12 < x < 0.27 obtaining a very small lattice expansion. The system shows a miscibility gap in the range 0.02 < x < 0.12, which supports the fact that the system is in the proximity of a lattice instability expected at the 2.5 Lifshitz phase transition²¹ in agreement with pressure elect measurements². The elect of the Sc doping is to shift the chemical potential toward the ETT and the top of the band. However the rigid band model is not appropriate since we expect that the

Sc substitution increases the sp^2 (B)-d (Sc) hybridization and the dispersion of the band.

In the M g_{1} $_xSc_xB_2$ samples the E_{2g} R am an mode shows a large hardening and narrowing in comparison with M gB_2 while the lattice expands, that indicates a drastic reduction of the K ohn anomaly in the E_{2g} longitudinal optical mode. This elect has been associated with the tuning of the Fermilevel beyond the critical energy for the ETT where the two dimensional topology of the

Ferm i surface changes to a three dim ensional topology. The critical tem perature in the M $q_1 \times Sc_x B_2$ sam ples has been found in the range 30-6 K as in the case of Alsubstituted sam ples in the regim ewhere the Ferm isurface of the band has a 3D topology beyond the 2D /3D ETT 6 . The high values of T c in this multi-band superconductor are associated with the key role of the non-diagonal interchannel pairing term and coulom b pseudo-potential term as in the case of Alsubstitution 23,24. These new data support the key role of the electronic structure controlling the resonant enhachem ent of the exchange like interband coupling term in a two-gap superconductor. This occurs when the chemical potential is tuned in an energy window around the 2D/3D electronic topological transition in one of the two Ferm i surface portions giving the shape resonance²⁵ that pushes up the critical tem perature.

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J. Nagam atsu, N. Nakagawa, T. Muranaka, Y. Zenitani, and J. Akim itsu, Nature 410, 63 (2001).

² C.Buzea and T.Yam ashita, Supercond.Sci.Technol.14, R115 (2001).

³ R.J.Cava, H.W. Zandbergen, and K. Inum aru, Physica C 385, 8-15 (2003).

⁴ J.S.Slusky, N.Rogado, K.A.Regan, M.A.Hayward, P. Khalifah, T.He, K.Inum aru, S.Loureiro, M.Haas, H.W. Zandbergen, and R.J.Cava, Nature 410, 343 (2001).

S. Agrestini, D. Di Castro, M. Sansone, N. L. Saini, A. Saccone, S. De Negri, M. Giovannini, M. Colapietro, A Bianconi, J. Phys.: Condens. Matter 13, 11689 (2001).

⁶ A.Bianconi, D.DiCastro, S.Agrestini, G.Campi, N.L. Saini, A.Saccone, S.DeNegriand M.Giovannini, J.Phys.: Condens. Matter 13, 7383 (2001); A.Bianconi, D.DiCastro, S.Agrestini, G.Zangari and N.L.Saini, A.Saccone, S.DeNegri, M.Giovannini G.Profeta, A.Continenza, G.Satta, S.Massidda, A.Cassetta, A.Pieri, M.Colapietro, Phys.Rev.B 65, 174515 (2002).

J.Q.Li, L.Li, F.M.Liu, C.Dong, J.Y.X iang, and Z.X. Zhao, Phys Rev. B 66, 012511 (2002).

⁸ S. Lee, T. Masui, A. Yamamoto, H. Uchiyama and S. Tajima, Physica C 397, 7 (2003); S. M. Kazakov, J. Karpinski, J. Jun, P. Geiser, N. D. Zhigadlo, R. Puzniak, A. V. Mironov, cond-mat/0304656.

I.I.M azin, and V.P.Antropov, Physica C 385, 49 (2003).
 K.P.Bohnen, R. Heid, and B. Renker, Phys. Rev. Lett.

^{86, 5771 (2001).}

P.Postorino, A.Congeduti, P.Dore, A.Nucara, A.Bianconi, D.DiCastro, S.DeNegriand A.Saccone, Phys.Rev. B 65,020507 (2001).

B. Renker, K. B. Bohnen, R. Heid, and D. Emst, H. Schober and M. Koza P. Adelmann, P. Schweiss, and T. Wolf, Phys. Rev. Lett. 88, 067001 (2002).

D.DiCastro, S.Agrestini, G.Campi, A.Cassetta, M.Colapietro, A.Congeduti, A.Continenza, S.De Negri, M.Giovannini, S.Massidda, M.Nardone, A.Pieri, P.Postorino, G.Profeta, A.Saccone, N.L.Saini, G.Satta, A.Bianconi, Europhys.Lett. 58, 278 (2002).

¹⁴ G.Gruner, \D ensity W aves in solids" Perseus Publ, Cam bridge, M assachusetts 2000).

¹⁵ M .E.Flatte, Phys.Rev.50,1190 (1994).

- A. Shukla, M. Calandra, M. d'Astuto, M. Lazzeri, F. Mauri, C. Bellin, M. Krisch, J. Karpinski, S. M. Kazakov, J. Jun, D. Daghero, and K. Parlinski, Phys. Rev. Lett. 90, 095506 (2003).
- ¹⁷ A Q R. Baron, H. Uchiyama, Y. Tanaka, S. Tsutsui, D. Ishikawa, S. Lee, R. Heid, K. P. Bohnen, S. Tajima, T. Ishikawa, cond-mat/0309123 (2003).
- W.E.Pickett, Brazilian Journal of Physics 33, 695 (2003); J.M.An, S.Y.Savrasov, H.Rosner, and W.E.Pickett, Phys.Rev.B 66, 220502-R (2002); W.E.Pickett, J.M. An, H.Rosner, and S.Y.Savrasov, Physica C 387, 117 (2003) and references therein.
- ¹⁹ S. Tsuda, T. Yokoya, Y. Takano, H. Kito, A. Matsushita, F. Yin, J. Itoh, H. Harima, and S. Shin, Phys. Rev. Lett. 91, 12700 (2003).

- A. Carrington, P. J. Messon, J. R. Cooper, L. Balicas, N. E. Hussey, E. A. Yelland, S. Lee, A. Yam am oto, S. Tajima, S. M. Kazakov, and J. Karpinski, Phys. Rev. Lett. 91, 037003 (2003).
- $^{21}\,$ I.M .Lifshitz, Soviet Physics JEPT 11, 1130 (1960).
- ²² A. F. Goncharov, V. V. Struzhkin, Physica C 385 117 (2003).
- A. Bussmann-Holder and A. Bianconi, Phys. Rev. B 67, 132509 (2003).
- ²⁴ G.A.Ummarino, R.S.Gonnelli, S.Massidda, A.Bianconi, Physica C 407 121 (2004).
- A.Bianconi, A.Valletta, A.Perali and N.L.Saini, Physica C 296, 269 (1998).

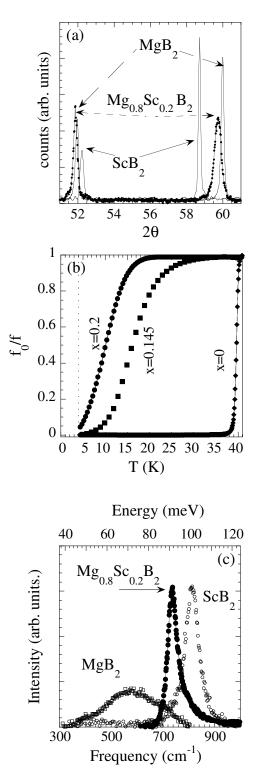


FIG.1: The X-ray di raction patterns in the range of the (001) and (110) re ections (panela), the superconducting transition measured by complex resistivity (panelb), and the Raman spectra (panelc) are shown for representative M g_1 x Sc_xB_2 samples compared with M gB_2 and ScB_2 .

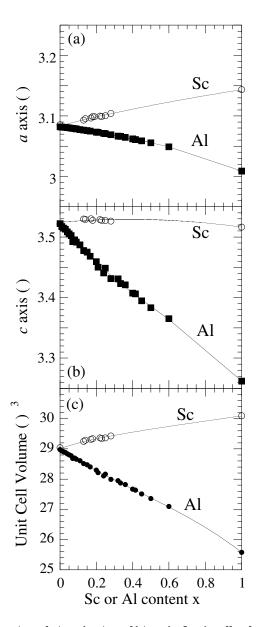


FIG.2: Changes of lattice parameters a (panela) and c (panelb) and of unit cell volume (panelc) as a function of Sc content x in M g_1 $_x$ Sc $_x$ B $_2$.

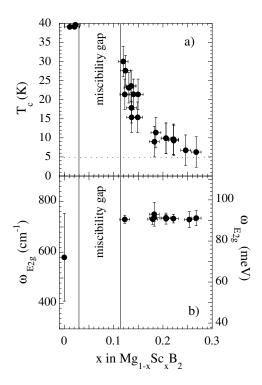


FIG. 3: Evolution of the superconducting critical temperature T_c (panela), the frequency $!_{E_{2g}}$ (panelb) of the E_{2g} R am an line as a function of x in M g_{1-x} Sc $_x$ B $_2$. The superconductive transition width and the E_{2g} peak half-width are indicated as error bars respectively in panela and panelb.

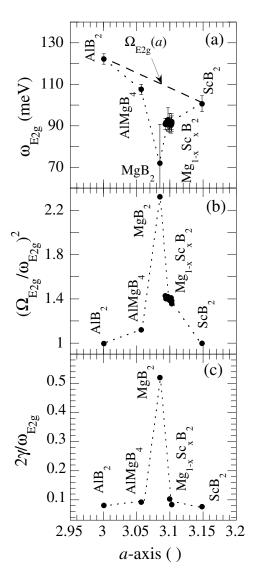


FIG. 4: Variation of the frequency of the E $_{2g}$ R am an line as function of the lattice parameter a for dierent diborides (panel a). The softening and broadening of the E $_{2g}$ m ode due to the K ohn anomaly is given by the energy ratio $(E_{2g}(a))^2$ (panelb) and the ratio $E_{2g}(a)$ (panelc) where $E_{2g}(a)$ is the R am an line-width.